USB OTG Companion Device with V_{BUS} Over Voltage, Over Current Protection, and Four Channel ESD Clamps

Check for Samples: TPD4S214

FEATURES

- **Input Voltage Protection at V_{BUS} from –7 V to 30 V**
- **Low $R_{DS(ON)}$ N-CH FET Switch for High Efficiency**
- **Compliant with USB2.0 and USB3.0 OTG spec**
- **User Adjustable Current Limit From 250 mA to Beyond 1.2 A**
- **Built-in Soft-start**
- **Reverse Current Blocking**
- **Over Voltage Lock Out for V_{BUS}**
- **Under Voltage Lock Out for V_{OTG_IN}**
- **Thermal Shutdown and Short Circuit Protection**
- **Auto Retry on any Fault; no Latching off States**
- **Integrated V_{BUS} Detection Circuit**
- **Low Capacitance TVS ESD Clamp for USB2.0 High Speed Data Rate**
- **Internal 16ms Startup Delay**

- **ESD Performance D+, D-, ID, V_{BUS} PINS**
  - **±15-kV Contact Discharge (IEC 61000-4-2)**
  - **±15-kV Air Gap Discharge (IEC 61000-4-2)**
- **Space Saving WCSP (12-YFF) Package**

APPLICATIONS

- **Cell Phones**
- **Tablet, eBook**
- **Set-Top Box**
- **Portable Media Players**
- **Digital Camera**

YFF PACKAGE
(TOP SIDE/SEE-THROUGH VIEW)

12-YFF Pin Proposal

	1	2	3
A	V_{OTG_IN}	DET	VBUS
B	V_{OTG_IN}	FLT\	VBUS
C	EN	GND	ID
D	ADJ	D-	D+

1.39-mm
1.69-mm
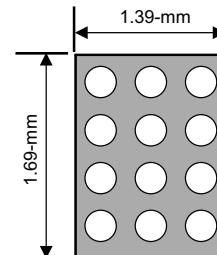
DESCRIPTION

The TPD4S214 is a single-chip protection solution for USB On-the-Go and other current limited USB applications. This device includes an integrated low ($R_{DS(ON)}$) N-channel current limited switch for OTG current supply to peripheral devices. TPD4S214 offers low capacitance TVS ESD clamps for the D+, D-, ID pins for both USB2.0 and USB3.0 applications. The VBUS pin can handle continuous voltage ranging from –7 V to 30 V. The over voltage lock-out (OVLO) at the VBUS pin ensures that if there is a fault condition at the V_{BUS} line, the TPD4S214 is able to isolate it and protects the internal circuitry from damage. Similarly, the under voltage lock out (UVLO) at the V_{OTG_IN} pin ensures that there is no power drain from the internal OTG supply to external V_{BUS} if V_{OTG_IN} droops below safe operating level.

When EN is high, the OTG switch is activated and the $\overline{FLT}$ pin indicates whether there is a fault condition. The soft start feature waits 16 ms to turn on the OTG switch after all operating conditions are met. The $\overline{FLT}$ pin asserts low during any one of the following fault conditions: OVLO ($V_{BUS} > V_{OVLO}$), UVLO condition ($V_{OTG\_IN} < V_{UVLO}$) over temperature, over current, short circuit condition, or reverse-current-condition ($V_{BUS} > V_{OTG\_IN}$). The OTG switch is turned off during any fault condition. Once the switch is turned off, the IC periodically rechecks the faults internally. If the IC returns to normal operating conditions, the switch turns back on and $\overline{FLT}$ is reset to high.

There is also a V_{BUS} detection feature for facilitating USB communication between USB host and peripheral device. See Table 2 for detection scheme. If this is not used, DET pin can be either floating or connected to ground.

⚠ Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

T$_A$	PACKAGE[1][2]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	WCSP – YFF (0.4-mm pitch)	Tape and reel	TPD4S214YFFR	B3214

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

CIRCUIT SCHEMATIC DIAGRAM
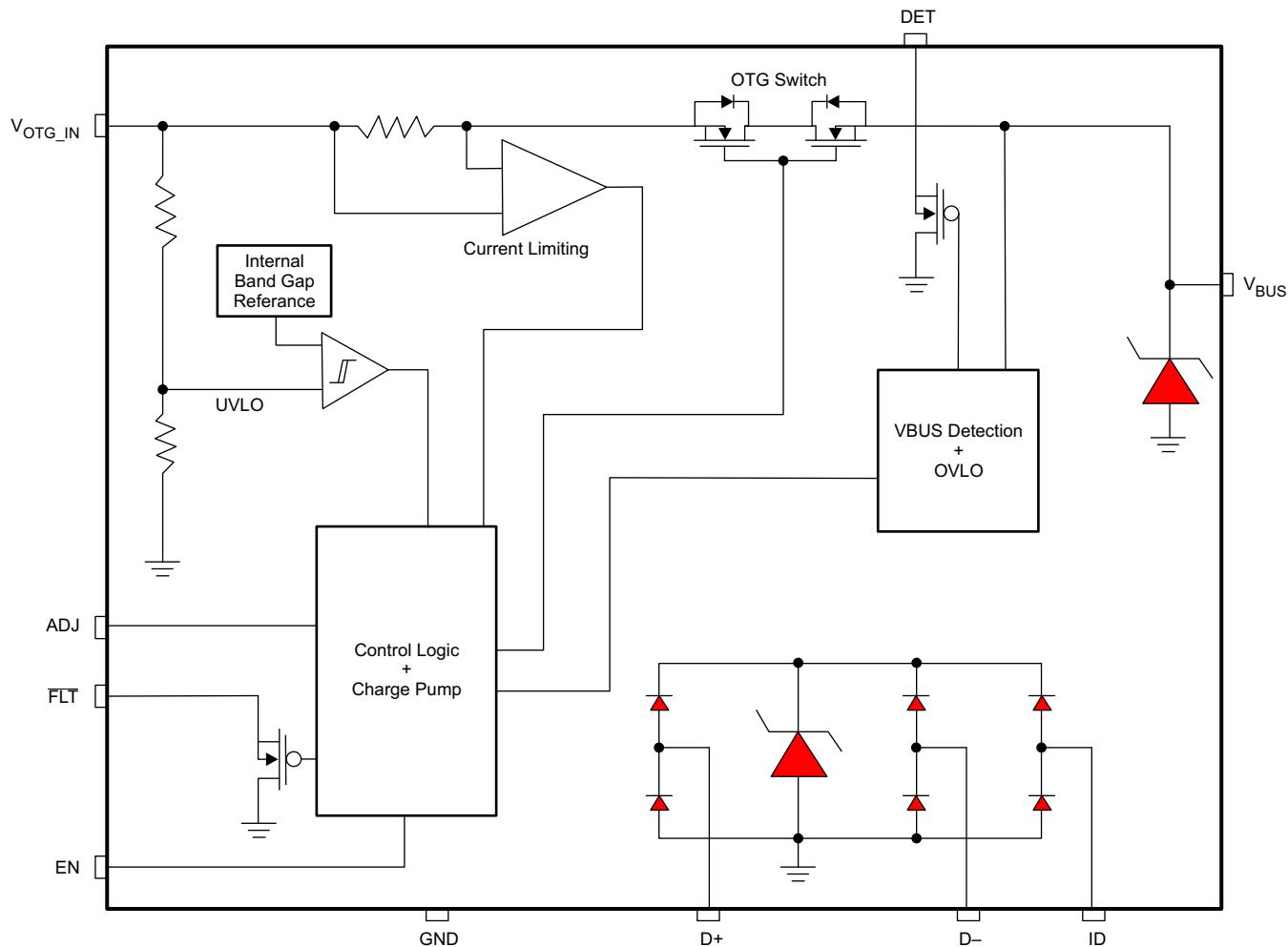
Figure 1. Circuit Schematic

Product Folder Links: *TPD4S214*

Table 1. Device Operation

EN	V_{OTG_IN}	V_{BUS}	OCP	OTP	OTG SW	$\overline{FLT}$	FAULT CONDITION
X	0	0	F	F	OFF	L	SW Disabled
X	X	X	X	T	OFF	L	Over Temperature
H	X	X	T	X	OFF	L	Over Current
H	$V_{OTG\_IN} > V_{UVLO}$	$V_{BUS} > V_{OTG\_IN}$	F	F	OFF	L	Reverse-current
H	X	$V_{BUS} > V_{OVLO}$	F	F	OFF	L	V_{BUS} over-voltage
H	$V_{OTG\_IN} < V_{UVLO}$	X	F	F	OFF	L	V_{OTG_IN} under-voltage
H	$V_{OTG\_IN} > V_{BUS}$ and $V_{OTG\_IN} > V_{UVLO}$	$V_{SHORT} < V_{BUS} < V_{OTG\_IN}$ and $V_{SHORT} < V_{BUS} < V_{OVLO}$	F	F	ON	H	Normal (SW Enabled)

Table 2. V_{BUS} Detection Scheme[1]

EN	VOTG_IN (V_{BUS} Detect Power)	V_{BUS}	DET	Condition
X	X	$V_{BUS\_VALID}- < V_{BUS} < V_{BUS\_VALID}+$	H	V_{BUS} within V_{BUS_VALID}
X	X	$V_{BUS\_VALID}+ > V_{BUS}$ or $V_{BUS} > V_{BUS\_VALID}+$	L	V_{BUS} outside of V_{BUS_VALID}

(1)   X = Don't Care, H = Signal High, and L = Signal Low

PIN FUNCTIONS

PIN				DESCRIPTION
NAME	YFF	DRC	TYPE	
D–	D2	TBD	I/O	USB data–
D+	D3	TBD	I/O	USB data+
ID	C3	TBD	I/O	USB ID signal
$\overline{FLT}$	B2	TBD	O	Open-Drain Output. Connect a pullup resistor from FLT\ to the supply voltage of the host system.
ADJ	D1	TBD	I	Attach external resistor to adjust the current limit
EN	C1	TBD	I	Enable Input. Drive EN high to enable the OTG switch.
V_{BUS}	A3, B3	TBD	O	USB Power Output
V_{OTG_IN}	A1, B1	TBD	I	USB OTG Supply Input
DET	A2	TBD	O	Open-Drain Output. Connect a pullup resistor from DET to the supply voltage of the host system.
GND	C2	Thermal Pad	Ground	Connect to PCB ground plane

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ABSOLUTE MAXIMUM RATINGS [(1)(2)]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{OTG_IN}, ADJ, EN	Input voltage		−0.5	7	V
V_{BUS}	Output voltage to USB connector		−7	30	
$\overline{FLT}$, DET	Output voltage		−0.5	7	
	Input clamp current	$V_I < 0$		-50	mA
	I_{OUT} Continuous current through $\overline{FLT}$ and DET output			10	mA
	I_{GND} Continuous current through GND			100	mA
	$T_{J(max)}$ maximum junction temperature		−65	150	°C
D+, D-, ID, V_{BUS} pins	IEC 61000-4-2 Contact Discharge at 25°C			±15	kV
D+, D-, ID, V_{BUS} pins	IEC 61000-4-2 Air-gap Discharge at 25°C			±15	kV
All pins	Human-Body Model at 25°C			±2	kV
D+, D-, ID pins	Peak Pulse Current (tp = 8/20 µs) at 25°C			7.8	A
D+, D-, ID pins	Peak Pulse Power (tp = 8/20 µs) at 25°C			84	W

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

			MIN	TYP	MAX	UNIT
T_A	Operating free-air temperature		-40		85	°C
V_{IH}	High-level input voltage EN		1.2			V
V_{IL}	Low-level input voltage EN				0.4	V
t_{EN}	EN ramp rate for proper turn on	Valid ramp rate is between 10us and 100ms, rising and falling	0.01		100	ms
t_{UVLO_SLEW}	V_{OTG_IN} ramp rate for proper UVLO operation	Valid ramp rate is between 10us and 100ms, rising and falling	0.01		100	ms
t_{OVLO_SLEW}	V_{BUS} ramp rate for proper OVLO operation	Valid ramp rate is between 10us and 100ms, rising and falling	0.01		100	ms
$T_{A\_VBUS\_ATT}$	Time to detect V_{BUS} device attachment and turn on DET				200	ms

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

THERMAL METRICS[(1)]			YFF	UNITS
$θ_{JA}$	Package thermal impedance	Package thermal impedance	89.1	°C/W

(1) The published $θ_{JA}$ was modeled assuming a 76mm x 114mm PCB with 4 copper layers and the exposed land pad of the PCB has thermal vias connecting the exposed center pad of the package to an internal GND plane for maximum heat dissipation. For more information about traditional and new thermal metrics, see the IC Package Metrics application report, SPRA953A.

Product Folder Links: *TPD4S214*

ELECTRICAL CHARACTERISTICS FOR EN, $\overline{FLT}$, DET, D+, D–, V_{BUS}, ID Pins

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{IL_EN}	EN pin input leakage current	EN = 3.3 V			1	µA
I_{OL}	FLT\, DET pin output leakage current	$\overline{FLT}$, DET = 3.6 V			1	µA
V_{OL_FLT}	Low-level output voltage FLT\	V_{BUS} or V_{OTG_IN} = 5 V or 0 V I_{OL} = 100 µA			100	mV
V_{OL_DET}	Low-level output voltage DET	V_{BUS} and V_{OTG_IN} = 5 V or 0 V I_{OL} = 100 µA			100	mV
C_{EN}	Enable capacitance	V_{BIAS} = 1.8 V, f = 1 MHz, 30 mVpp ripple, V_{OTG_IN} = 5 V		4.5		pF
V_D	Diode forward voltage D+, D–, ID pins; lower clamp diode	I_O = 8 mA			0.95	V
I_{L_D}	Leakage current on D+, D–, ID Pins	D+, D–, ID = 3.3 V			100	nA
ΔC_{IO}	Differential capacitance between the D+, D– lines	V_{BIAS} = 1.8 V, f = 1 MHz, 30 mVpp ripple, V_{OTG_IN} = 5 V			0.04	pF
C_{IO}	Capacitance to GND for the D+, D– lines	V_{BIAS} = 1.8 V, f = 1 MHz, 30 mVpp ripple, V_{OTG_IN} = 5 V		1.9		pF
	Capacitance to GND for the ID lines			1.9		
V_{BR}	Breakdown voltage D+, D–, ID pins	I_{br} = 1 mA	6			V
	Breakdown voltage on Vbus	I_{br} = 1 mA	33			V
R_{DYN}	Dynamic on resistance D+, D–, ID clamps			1		Ω

ELECTRICAL CHARACTERISTICS FOR UVLO / OVLO

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT UNDER-VOLTAGE LOCKOUT						
V_{UVLO+}	Under-voltage lock-out, input power detected threshold rising	V_{OTG_IN} increasing from 0 V to 5 V, No load on V_{BUS} pin	3.4	3.6	3.8	V
V_{UVLO-}	Under-voltage lock-out, input power detected threshold falling	V_{OTG_IN} decreasing from 5 V to 0 V, No load on V_{BUS} pin	3.0	3.2	3.5	V
$V_{HYS-UVLO}$	Hysteresis on UVLO	Δ of V_{UVLO+} and V_{UVLO-}		260		mV
T_{RUVLO}	Recovery time from UVLO	V_{OTG_IN} increasing from 0V to 5V, No load on V_{BUS} pin; time from V_{OTG_IN} = V_{UVLO+} to $\overline{FLT}$ toggles high		18		ms
T_{RESP_UVLO}	Response time for UVLO	V_{OTG_IN} decreasing from 5V to 0V, No load on V_{BUS} pin; time from V_{OTG_IN} = V_{UVLO-} to FLT\ toggles low		0.18		µs
OUTPUT OVERVOLTAGE LOCKOUT						
V_{OVP+}	OVLO rising threshold	Both V_{OTG_IN} and V_{BUS} increasing from 5 V to 7 V	5.55	6.15	6.45	V
V_{OVP-}	OVLO falling threshold	Both V_{OTG_IN} and V_{BUS} decreasing from 7 V to 5 V	5.4	6	6.3	V
$V_{HYS-OVP}$	Hysteresis on OVLO	Δ of V_{UVLO+} and V_{UVLO-}		100		mV
T_{ROVLO}	Recovery time from OVLO	Both V_{OTG_IN} and V_{BUS} decreasing from 7 V to 5 V, V_{OTG_IN} = 5 V; time from V_{BUS} = V_{OVP-} to $\overline{FLT}$ toggles high		9		ms
T_{RESP_OVLO}	Response time for OVLO	Both V_{OTG_IN} and V_{BUS} increasing from 5 V to 7 V, V_{OTG_IN} = 5 V; time from V_{BUS} = V_{OVP+} to $\overline{FLT}$ toggles low		17		µs

ELECTRICAL CHARACTERISTICS FOR DET CIRCUITS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{BUS_VALID-}	Valid V_{BUS} voltage detect	V_{BUS} = 7 V to 0 V	2.7	2.9	3	V
V_{BUS_VALID+}	Valid V_{BUS} voltage detect	V_{BUS} = 0 V to 7 V	5.3	5.4	5.6	V
T_{DET_DELAY-}	VBUS detect propagation delay–	VBUS 0 V to 4 V, 200 ns ramp; VBUS = $V_{BUS\_VALID-\ MIN}$ to DET toggles high		4.9		µs
T_{DET_DELAY+}	VBUS detect propagation delay+	VBUS 6 V to 4 V, 200 ns ramp; VBUS = $V_{BUS\_VALID+\ MAX}$ to DET toggles low		1.8		µs

ELECTRICAL CHARACTERISTICS FOR OTG SWITCH

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
R_{DS_ON}	OTG switch resistance	V_{BUS} = 5 V, IOUT = 100 mA, R_{ADJ} = 75 kΩ[1]			263	290	mΩ
V_{DROP}	OTG switch voltage drop	V_{BUS} = 5 V, IOUT = 100 mA, R_{ADJ} = 75 kΩ			12.6	29	mV
$I_{OTG\_OFF\_30V}$	Leakage current at 30V	Measured at V_{OTG_IN}	V_{BUS} = 30 V, EN = 5 V, V_{OTG_IN} = 5 V		6		µA
			V_{BUS} = 30 V, EN = 5 V, V_{OTG_IN} = 0 V		11		nA
$I_{OTG\_OFF\_2V}$	Leakage current at–2V		V_{BUS} = -2 V, EN = 5 V, V_{OTG_IN} = 5 V		30		µA
I_{OTG_OFF}	Standby Leakage current		V_{BUS} = 0 V, EN = 0 V, V_{OTG_IN} = 5 V		32		µA
			V_{BUS} = 5 V, EN = 0 V, V_{OTG_IN} = 0 V		10		nA
I_{BUS_REV}	Reverse Leakage current		V_{BUS} = 5 V, EN = 5 V, V_{OTG_IN} = 0V		1		nA
			V_{BUS} = 5.5 V, EN = 5 V, V_{OTG_IN} = 5 V		6		µA
T_{ON}	Turn-ON time	R_L = 100 Ω, C_L = 1 uF, R_{ADJ} = 75 kΩ			16		ms
T_{OFF_EN}	Turn-OFF time	R_L = 100 Ω, C_L = 1 uF, R_{ADJ} = 75 kΩ, toggle EN			80		µs
T_{OFF_OTG}	Turn-OFF time	R_L = 100 Ω, C_L = 1 uF, R_{ADJ} = 75 kΩ, toggle V_{OTG_IN}			0.5		µs
T_{RISE}	Output rise time	R_L = 100 Ω, C_L = 1 uF, R_{ADJ} = 75 kΩ			137		µs
T_{FALL}	Output fall time	R_L = 100 Ω, C_L = 1 uF, R_{ADJ} = 75 kΩ			1.6		µs

(1) R_{DS_ON} is measured at 25°C

ELECTRICAL CHARACTERISTICS FOR CURRENT LIMIT and SHORT CIRCUIT PROTECTION

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I_{OCP}	Current−limit threshold (maximum DC output current IOUT delivered to load)	V_{OTG_IN} = 5 V	R_{ADJ} = 226 kΩ[1]	235	255	281	mA
			R_{ADJ} = 75 kΩ[1]	735	792	830	
			R_{ADJ} = 62 kΩ[1]	885	959	1005	
			R_{ADJ} = 45 kΩ[1]	1128	1200	1363	
T_{BLANK}	Blanking time after enable	V_{OTG_IN} = 5 V	RL = 1 Ω, CL = 1 uF, RADJ = 75 kΩ		4		ms
T_{DEGL}	Deglitch time while enabled	V_{OTG_IN} = 5 V, RL = 100 Ω, CL = 1 uF, RADJ = 75 kΩ, apply short to ground			9.4		ms
T_{DET_SC}	Response time to short circuit				10		µs
T_{REG}	Short circuit regulation time		Hiccup pulse width; auto-retry time		13		ms
T_{OCP}	Short circuit over current protection time		Hiccup pulse period		153		ms
V_{SHORT}	Short circuit threshold				4		V
I_{INRUSH}	Inrush current during a startup	See Figure 5 under test configuration	RL = 100 Ω, CL = 22 µF, RADJ = 75 kΩ		726		mA

(1) External resistor tolerance is ±1%

ELECTRICAL CHARACTERISTICS FOR REVERSE VOLTAGE PROTECTION

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{REV}	Reverse-voltage comparator trip point (at V_{BUS} port)	$V_{BUS} > V_{OTG\_IN}$		50		mV
T_{RRVP}	Time from reverse-voltage condition to MOSFET switch off and $\overline{FLG}$ = low			17.5		ms
T_{RREV}	Re-arming time			25		µs

SUPPLY CURRENT CONSUMPTION

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TYP	MAX	UNIT
$I_{VOTG\_IN}ON$	High-level V_{OTG_IN} operating current consumption	V_{OTG_IN} = 5 V, No load on V_{BUS}, EN = 5 V	RADJ = 75 kΩ	162	200	µA
			RADJ = 226 kΩ	150	200	µA

THERMAL SHUTDOWN

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	TYP	MAX	UNIT
T_{SHDN+}	Shutdown temp rising		141		ºC
T_{SHDN-}	Shutdown temp falling		125		ºC
T_{HYST}	Thermal-shutdown Hysteresis		16		ºC
P_{MAX}	Maximum power dissipation	V_{OTG_IN} = 5 V, R_{load} = 5 Ω, EN = 5 V, R_{ADJ} = 75 KΩ		0.16	W
T_{JMAX}	Junction Temp at max power dissipation			150	ºC

APPLICATION DIAGRAM
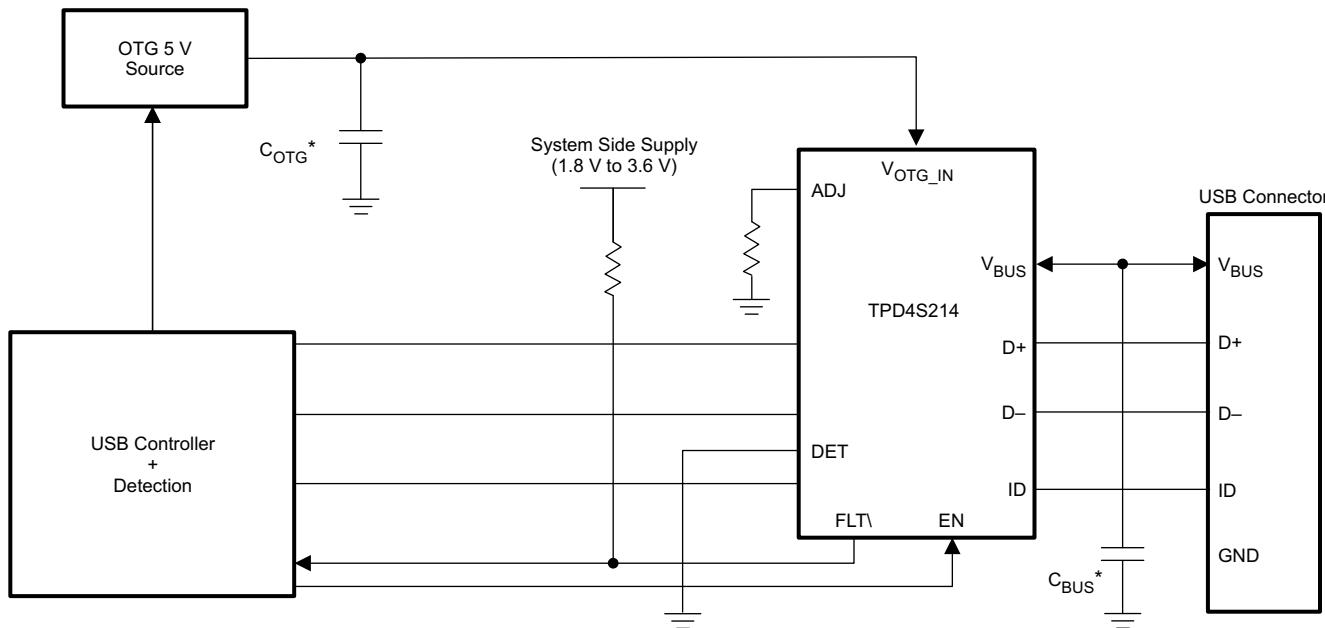
Figure 2. USB2.0 Application Diagram Without Using On-chip V_{BUS} Detect

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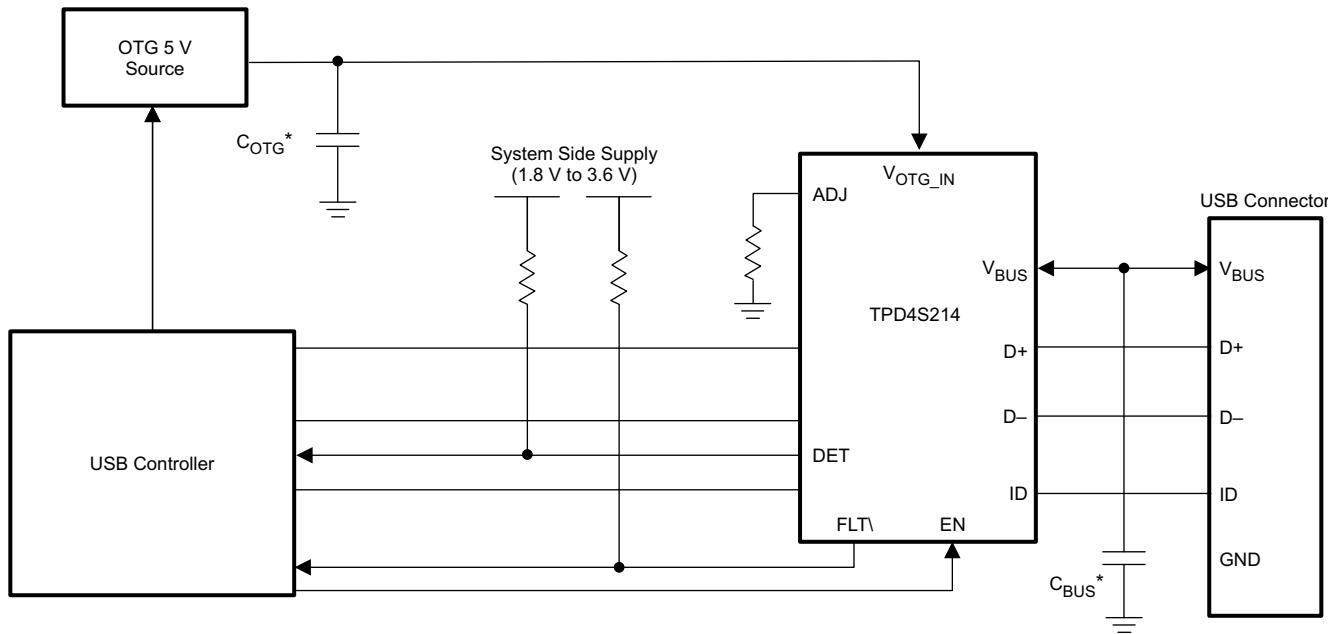
Figure 3. USB 2.0 Application Diagram Using On-chip V$_{BUS}$ Detect
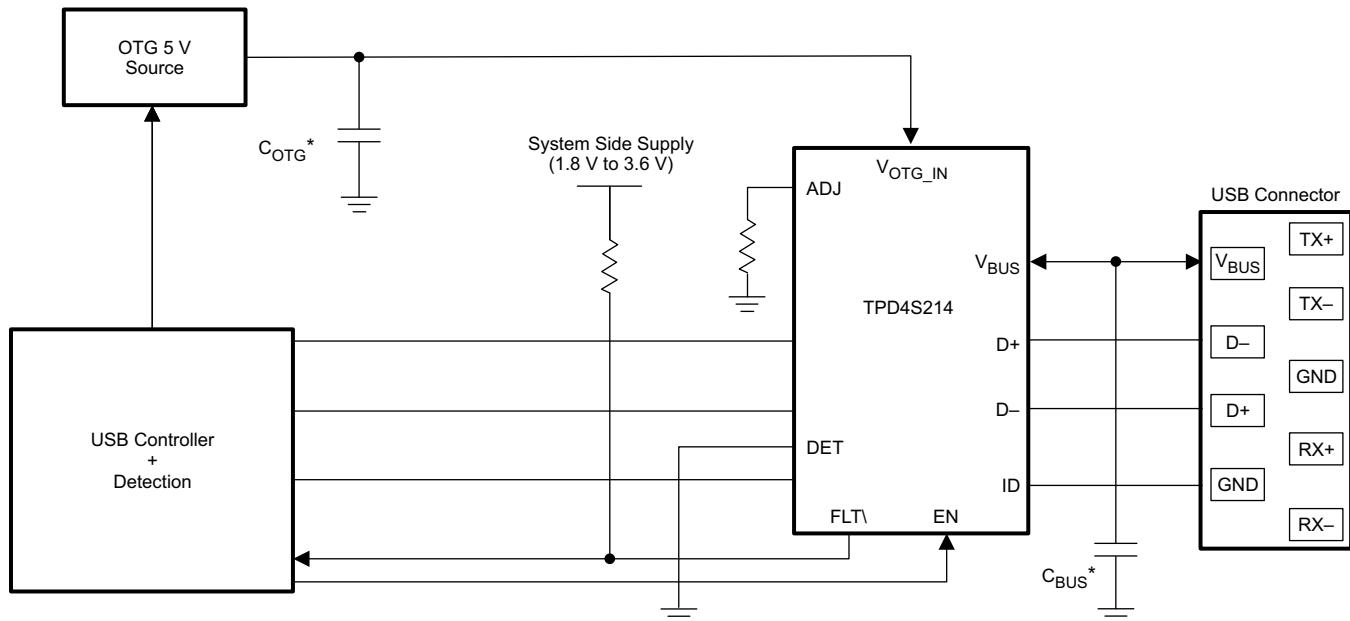
*C$_{BUS}$ and C$_{OTG}$ have minimum recommended values of 1 µF each

Figure 4. USB 3.0 Application Diagram Without Using On-chip V$_{BUS}$ Detect

Product Folder Links: *TPD4S214*

TEST CONFIGURATION
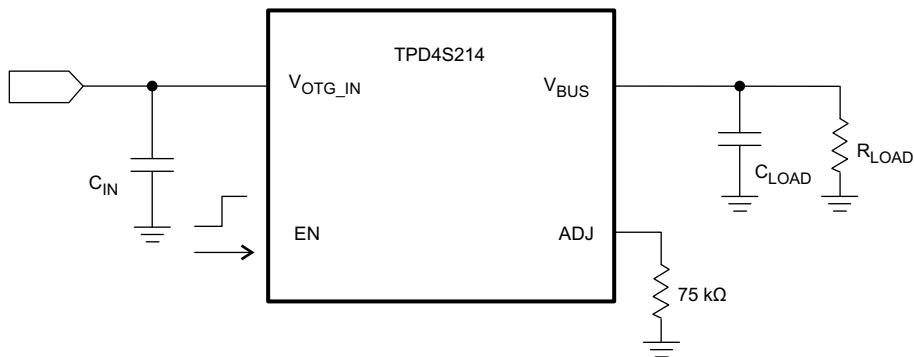
Figure 5. Inrush Current Test Configuration.

Enable is toggled from low to high. See the Application Information section for C_{IN} and C_{LOAD} value recommendations.

TYPICAL CHARACTERISTICS
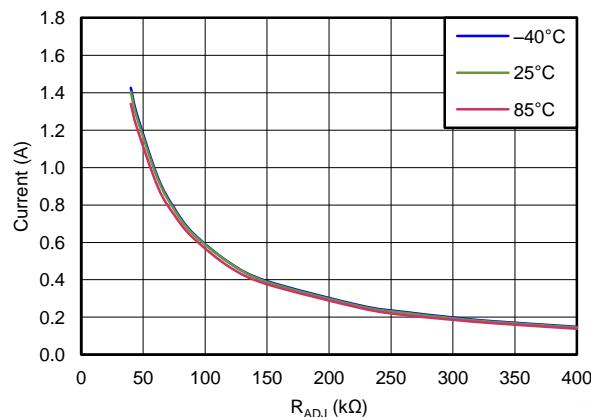
Figure 6. I_{OCP} vs. R_{ADJ}
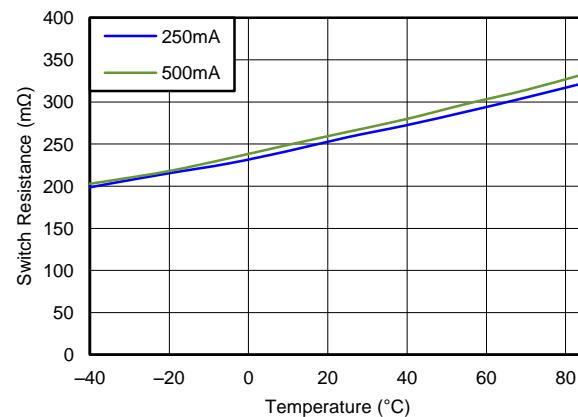
Figure 7. $3R_{DSON}$ vs. Temperature
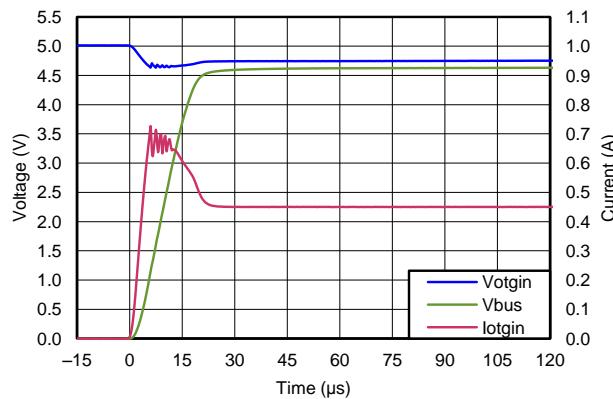
Figure 8. Inrush, R_{ADJ} = 75 kΩ
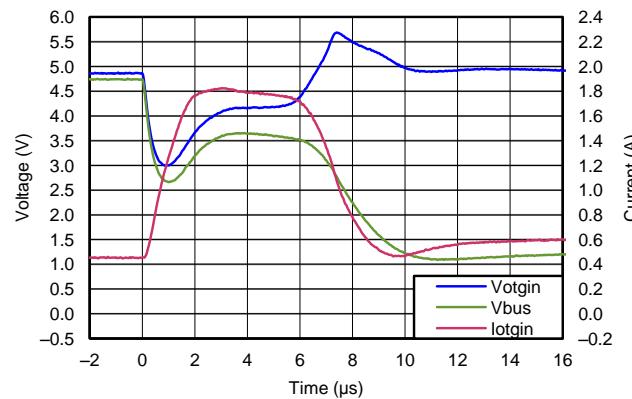
Figure 9. 10 Ω Load to Short, 2 µs
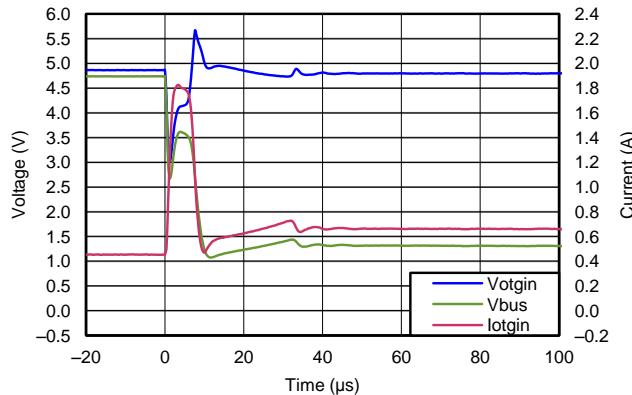
Figure 10. 10 Ω Load to Short, 20 µs
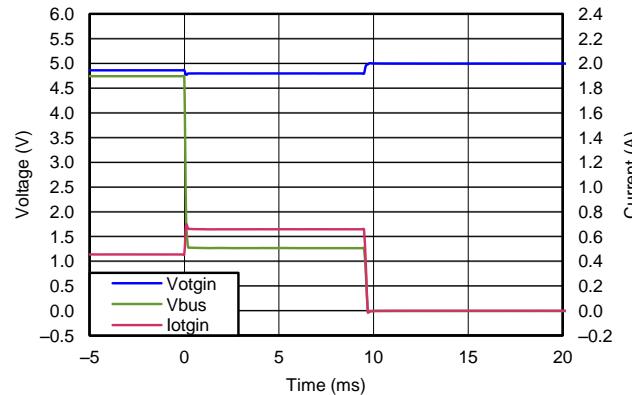
Figure 11. 10 Ω Load to Short, 5 ms

Product Folder Links: *TPD4S214*

TYPICAL CHARACTERISTICS (continued)
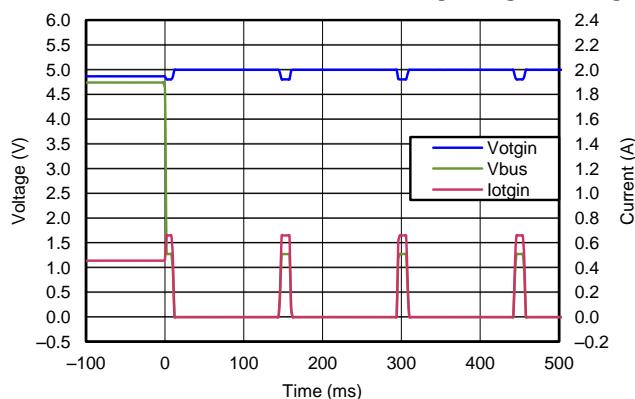

Figure 12. 10 Ω Load to Short, 100 ms
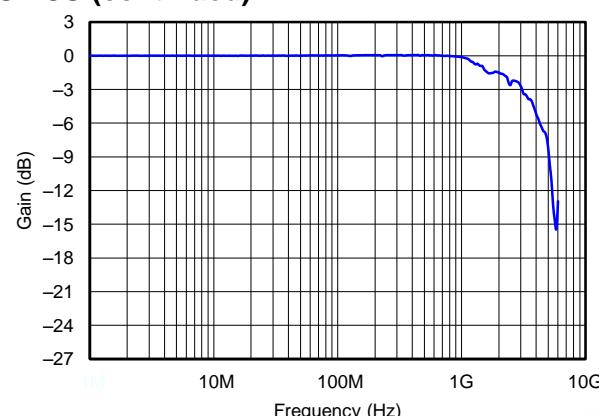

Figure 13. Data Line Insertion Loss
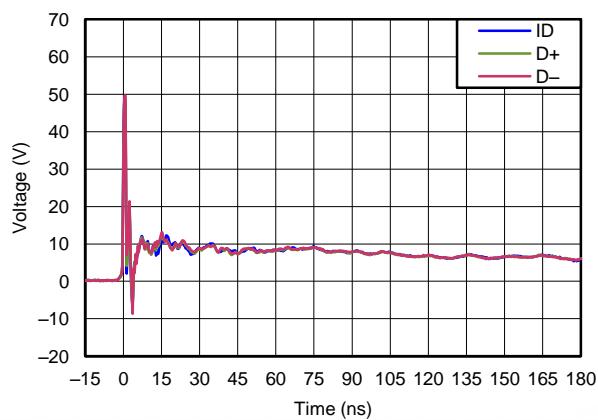
Figure 14. +8 kV Contact, 1 GHz
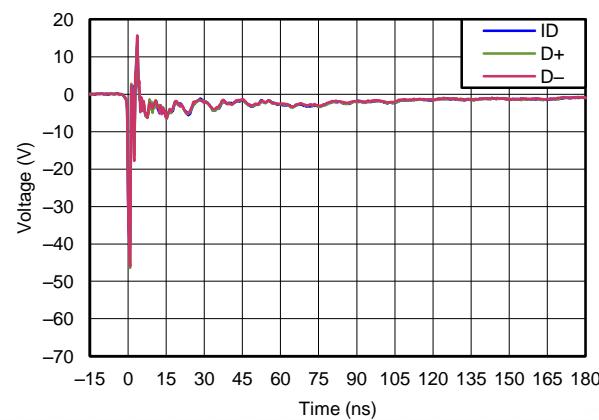
Figure 15. -8 kV Contact, 1 GHz
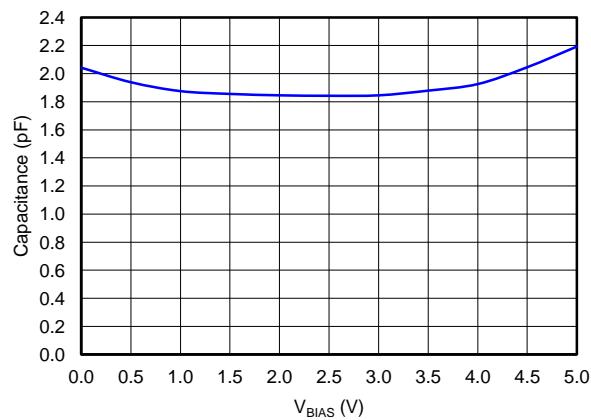
Figure 16. C_{IO} vs. V_{BIAS}, f = 1 MHz
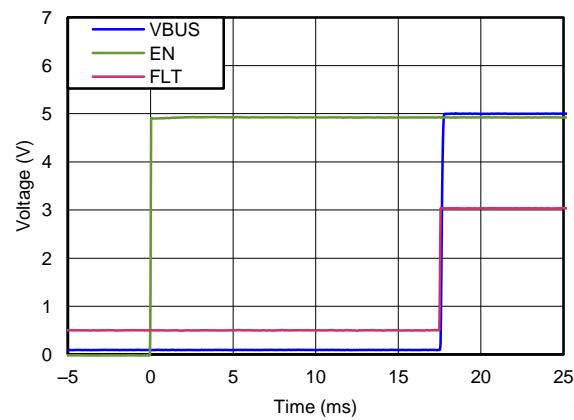

Figure 17. TPD4S214 Turn On Characteristics

TYPICAL CHARACTERISTICS (continued)

Figure 18. TPD4S214 Turn Off Characteristics

Figure 19. UVLO

Figure 20. OVLO

Figure 21. V$_{BUS}$ Valid Detect Upper

Figure 22. V$_{BUS}$ Valid Detect Lower

Figure 23. Eye Diagram with no EVM and no IC, Full USB2.0 Speed at 480 Mbps

Product Folder Links: *TPD4S214*
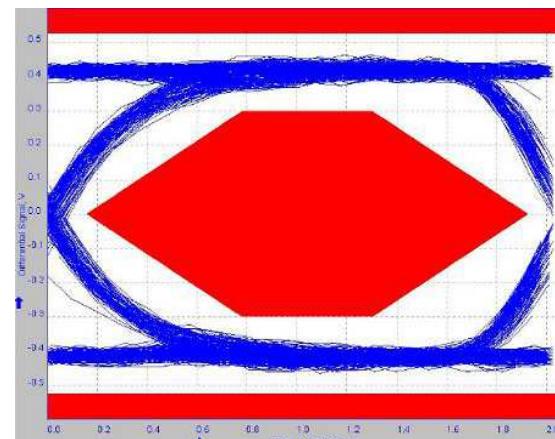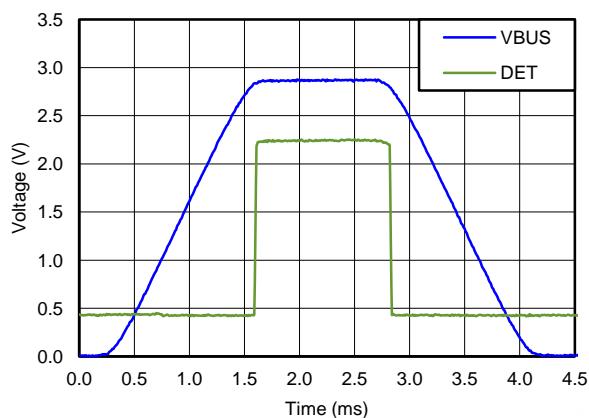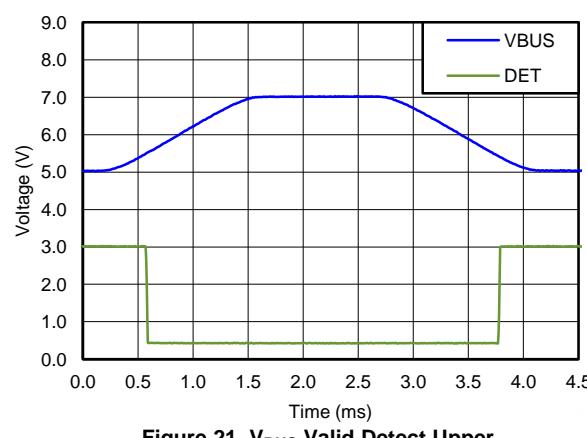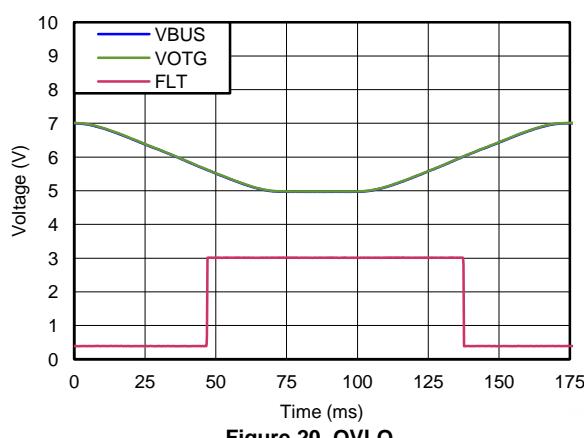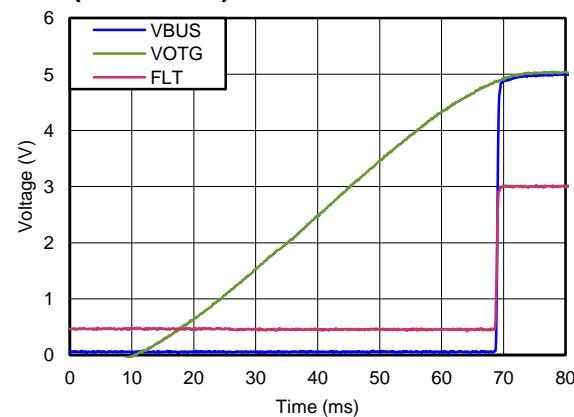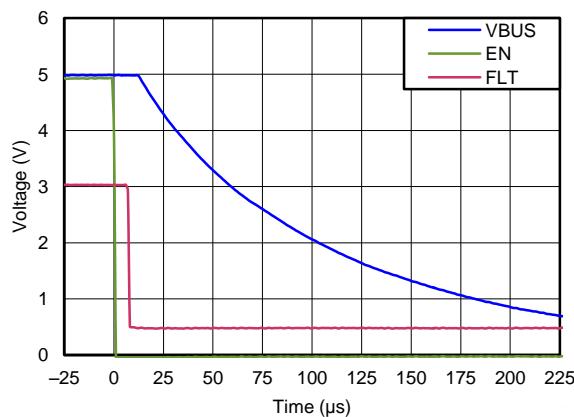
TYPICAL CHARACTERISTICS (continued)
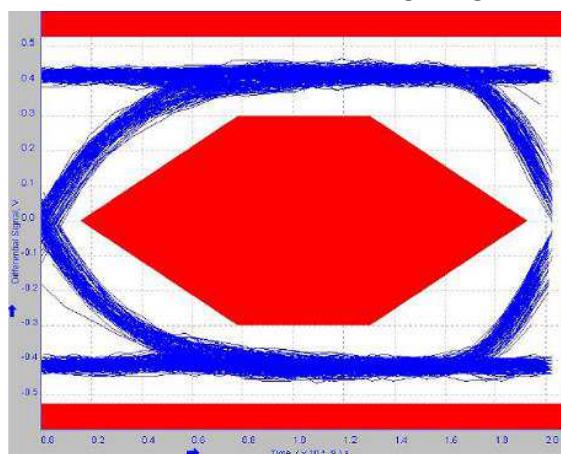
Figure 24. Eye Diagram with TPD4S214EVM but no IC, Full USB2.0 Speed at 480 Mbps
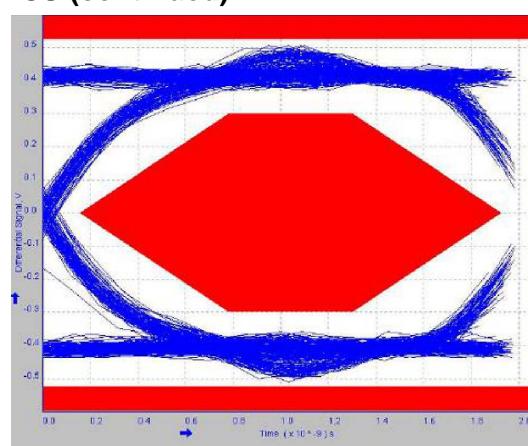
Figure 25. Eye Diagram with TPD4S214EVM and IC, Full USB2.0 Speed at 480 Mbps

APPLICATION INFORMATION

A USB OTG device's one and only connector is the AB receptacle, which accepts either an A or B plug. When an A-plug is inserted, the OTG device is called the A-device and when a B-plug is inserted it is called the B-device. A-device is often times referred to as "Targeted Host" and B-device as "USB peripheral". TPD4S214 supports an OTG device when TPD4S214's system is acting as an A-device and powering the USB interface. The TPD4S214 may also be used in non-OTG applications where it resides on the current source side.

Inrush Current Protection

As soon as TPD4S214 is enabled, its logic block detects the presence of any fault conditions highlighted in Table 1. In the absence of any fault condition, a counter waits for 16 ms, after which a trickle charge of 1 µA slowly turns on the main switch. During the inrush period, the peak inrush current will be limited to no more than the current limit set by the external resistor R_{ADJ}.

INPUT CAPACITOR (OPTIONAL)

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{OTG_IN} and GND. A 10-µF ceramic capacitor, C_{IN}, placed close to the pins, is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop during high-current application. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop.

OUTPUT CAPACITOR (OPTIONAL)

Due to the integrated body diode in the NMOS switch, a C_{IN} greater than C_{LOAD} is highly recommended. A C_{LOAD} greater than C_{IN} can cause V_{BUS} to exceed V_{OTG_IN} when the system supply is removed. A C_{IN} to C_{LOAD} ratio of 10 to 1 is recommended for minimizing V_{OTG_IN} dip caused by inrush currents during startup.

Current Limit

The TPD4S214 provides current limiting function, which is set by an external resistor connected from the ADJ pin to ground shown in Figure 26. The current limiting threshold I_{OCP} is set by the external resistor R_{ADJ}. Figure 6 shows the minimum, typical, and maximum current limit for a corresponding R_{ADJ} value with ±1% tolerance.
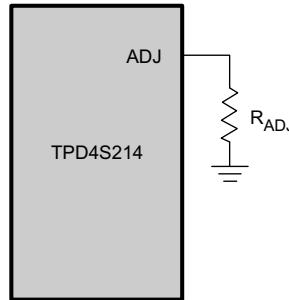
**Figure 26.**

$$R_{ADJ} = \frac{55.358}{I_{OCP}}$$

(1)

Where:

   R_{ADJ} = external resistor used to set the current limit (kΩ)
   I_{OCP} = current limit set by the external R_{ADJ} resistor (A)

R_{ADJ} is placed between the ADJ pin and ground, shown in the figure above, providing a minimum current limit between 250 mA and 1.2 A.

Product Folder Links: *TPD4S214*

V$_{BUS}$ Detection

There are several important protocols defined in [OTG and EH Supplement] that governs communication between Targeted Hosts (A-device) and USB peripherals (B-device). Communication between host and peripheral is usually done on the ID pin only. In case when two OTG devices that could both act as either host or peripheral are connected, measuring voltage level on V$_{BUS}$ will aid in the handshaking process. If an embedded host instead of a USB device is connected to the OTG device, OTG charging would not be required and the system's OTG source should remain off to conserve power. The TPD4S214 V$_{BUS}$ detection block aids power conservation and is powered from V$_{BUS}$. See figure 3. The DET pin is an open drain PMOS output with default state low.

In the event when an A-plug is attached, the system detects ID pin as FALSE, in which case ID pin resistance to ground is less than 10 Ω. For a B-plug, the system detects ID pin as TRUE and ID pin resistance to ground is greater than 100 kΩ. For the system to power a USB device through OTG switch once it is connected, voltage on V$_{BUS}$ should remain below V$_{BUS\_VALID\ MIN}$ within T$_{A\_VBUS\_ATT}$ of the ID pin becoming FALSE. After this event, the system confirms that the USB device requires power and enables both TPD4S214 and OTG source. However, if V$_{BUS\_VALID}$ is detected on V$_{BUS}$ within T$_{A\_VBUS\_ATT}$ of the ID pin becoming FALSE, there is either a system error or the device connected does not require charging. OTG source remains switched off and the entire sequence would restart when the system detects another FALSE on the ID pin.

Table 3. V$_{BUS}$ Detection scheme

EN	V$_{OTG\_IN}$ (V$_{BUS}$ Detect Power)	V$_{BUS}$	DET	Condition
X	X	V$_{BUS\_VALID}$- < V$_{BUS}$ < V$_{BUS\_VALID}$+	H	V$_{BUS}$ within V$_{BUS\_VALID}$
X	X	V$_{BUS\_VALID}$- > V$_{BUS}$ or V$_{BUS}$ > V$_{BUS\_VALID}$+	L	V$_{BUS}$ outside of V$_{BUS\_VALID}$

Figure 27 and Figure 28 shows suggested system level timing diagram for detecting V$_{BUS}$ according to [OTG and EH Supplement]. Figure 3 shows the application diagram. In Figure 27, DET pin remains low after ID pin becomes FALSE, indicating there is not an active voltage source on V$_{BUS}$. The USB controller proceeds to turn on OTG 5V source and the TPD4S214 respectively; this sequence is recommended because TPD4S214 is powered through the OTG source. After a period of t$_{ON}$, current starts to flow through the OTG switch and V$_{BUS}$ is ramped to the voltage level of V$_{OTG\_IN}$.
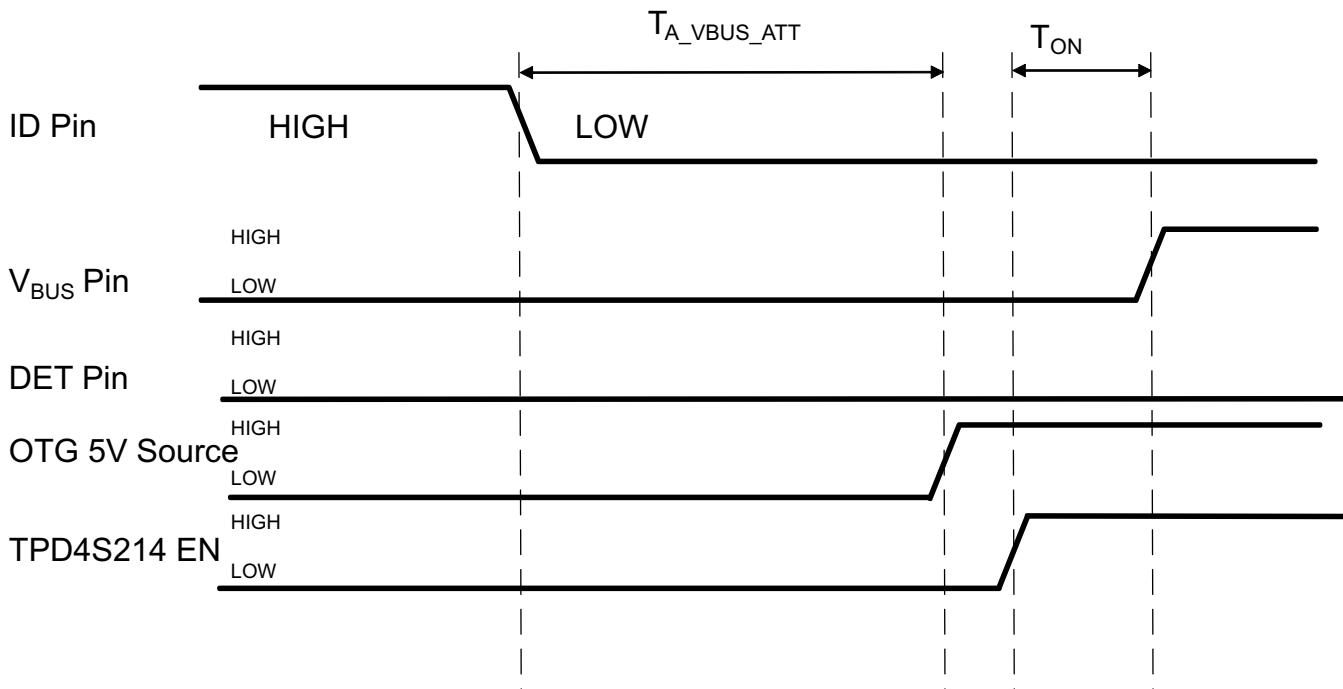
Figure 27. Timing Diagram for Valid USB Device

Product Folder Links: *TPD4S214*

In Figure 28, DET pin toggles high after an active voltage is detected on V_{BUS} within $T_{A\_VBUS\_ATT}$. This indicates that the USB device attached is not suitable for OTG charging and both OTV 5V source and TPD4S214 remain off.
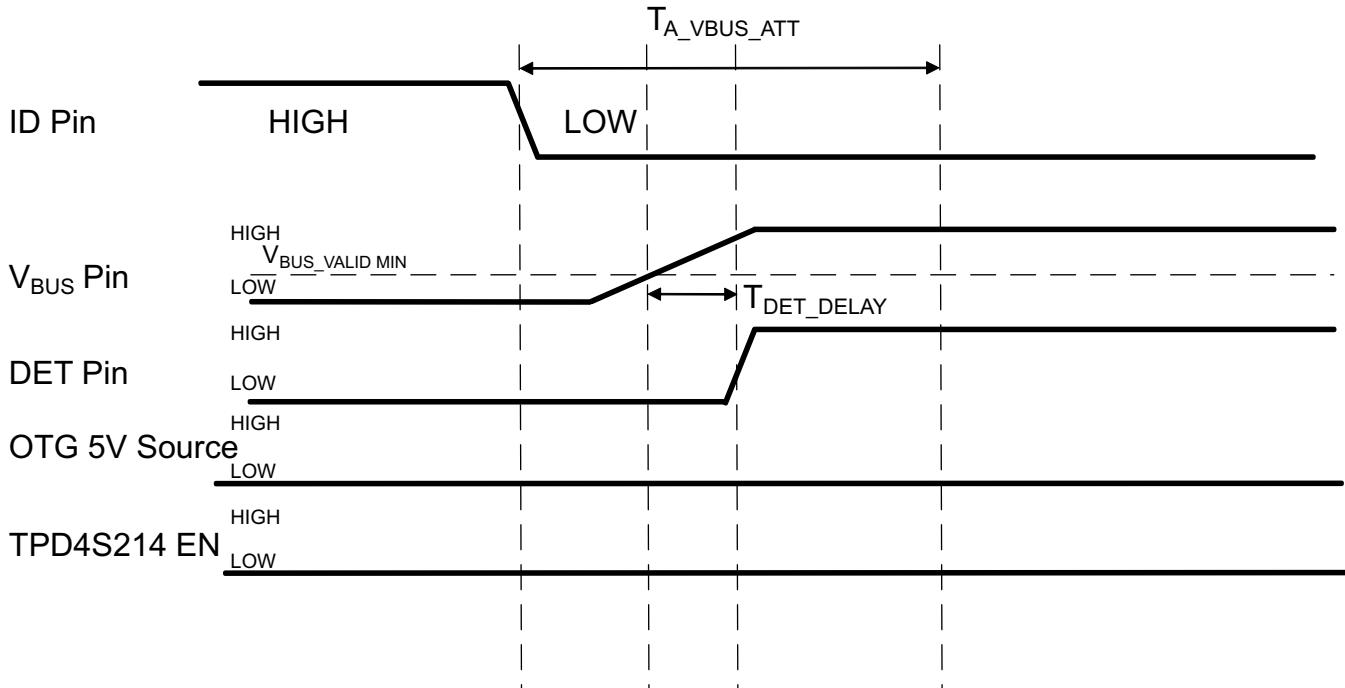
Figure 28. System Level Timing Diagram for invalid USB Device

Related Documents

OTG and EH Supplement] *On-The-Go and Embedded Host Supplement to the USB Revision 2.0 Specification*, July 14th, 2011. www.usb.org

REVISION HISTORY

Changes from Original (January 2013) to Revision A	**Page**
• Changed the Product Preview data sheet 1	

Changes from Revision A (February 2013) to Revision B	**Page**
• Changed the device From: Product Preview To: Production data 1	

Changes from Revision B (February 2013) to Revision C	**Page**
• Changed the YFF package dimensions 1	

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPD4S214AYFFR	PREVIEW	DSBGA	YFF	12	3000	TBD	Call TI	Call TI	-40 to 85		
TPD4S214YFFR	ACTIVE	DSBGA	YFF	12	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	B3214	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD4S214YFFR	DSBGA	YFF	12	3000	180.0	8.4	1.48	1.78	0.69	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD4S214YFFR	DSBGA	YFF	12	3000	210.0	185.0	35.0

YFF (R−XBGA−N12)   DIE−SIZE BALL GRID ARRAY

0,80

0,40

D

C

B

A

1   2   3

Bottom View

E

B

A

D

D

Ball A1 Index Area

0,20

1,20

0,40

12X Ø 0,30 / 0,20

⊕ Ø 0,015 Ⓜ C A B

0,625 Max

0,30 / 0,12

0,05 C

Seating Plane

C
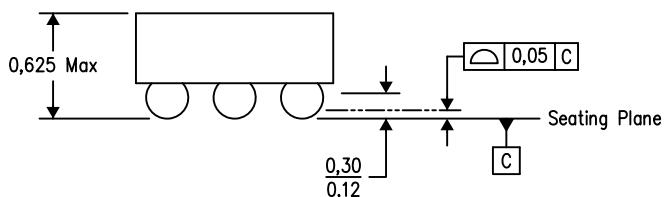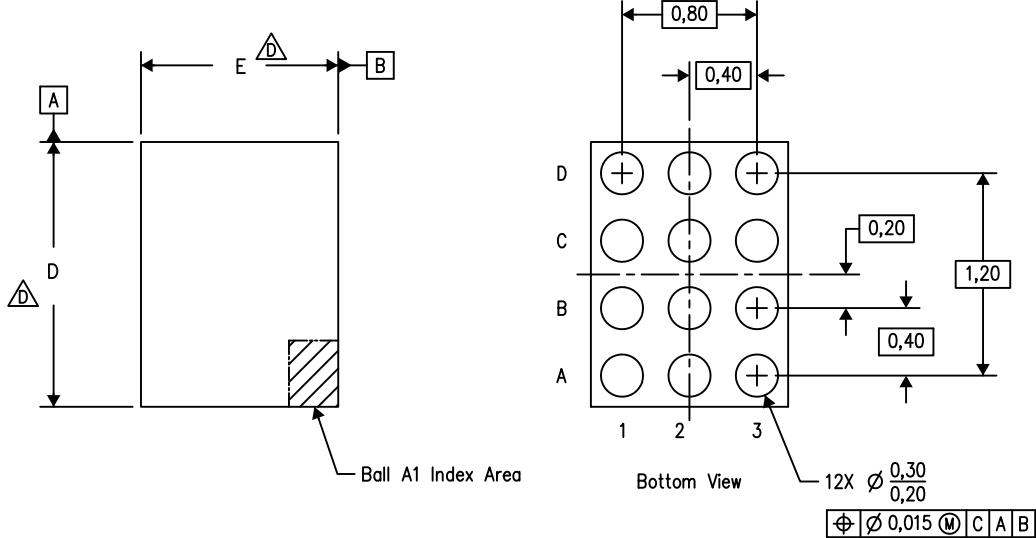
D: Max = 1.69 +/-0.03 mm
E: Max = 1.39 +/-0.03 mm

4207625−7/AK 11/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
          B. This drawing is subject to change without notice.
          C. NanoFree™ package configuration.
          D. The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version
              of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
          E. Reference Product Data Sheet for array population.
               3 x 4 matrix pattern is shown for illustration only.
          F. This package contains Pb−free balls.

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QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD4S214YFFR	DSBGA	YFF	12	3000	180.0	8.4	1.48	1.78	0.69	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD4S214YFFR	DSBGA	YFF	12	3000	182.0	182.0	17.0

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